

CMOS Dual Monostable Multivibrator

High-Voltage Types (20-Volt Rating)

■ CD4098B dual monostable multivibrator provides stable retriggerable/resettable one-shot operation for any fixed-voltage timing application.

An external resistor (R_X) and an external capacitor (C_X) control the timing for the circuit. Adjustment of R_X and C_X provides a wide range of output pulse widths from the Q and \bar{Q} terminals. The time delay from trigger input to output transition (trigger propagation delay) and the time delay from reset input to output transition (reset propagation delay) are independent of R_X and C_X .

Leading-edge-triggering (+TR) and trailing-edge-triggering (-TR) inputs are provided for triggering from either edge of an input pulse. An unused +TR input should be tied to V_{SS} . An unused -TR input should be tied to V_{DD} . A RESET (on low level) is provided for immediate termination of the output pulse or to prevent output pulses when power is turned on. An unused RESET input should be tied to V_{DD} . However, if an entire section of the CD4098B is not used, its RESET should be tied to V_{SS} . See Table I.

In normal operation the circuit triggers (extends the output pulse one period) on the application of each new trigger pulse. For operation in the non-retriggerable mode, \bar{Q} is connected to -TR when leading-edge triggering (+TR) is used or Q is connected to +TR when trailing-edge triggering (-TR) is used.

The time period (T) for this multivibrator can be approximated by: $T_X = \frac{1}{2} R_X C_X$ for $C_X \geq 0.01 \mu F$. Time periods as a function of R_X for values of C_X and V_{DD} are given in Fig. 8. Values of T vary from unit to unit and as a function of voltage, temperature, and $R_X C_X$.

The minimum value of external resistance, R_X , is 5 k Ω . The maximum value of external capacitance, C_X , is 100 μF . Fig. 9 shows time periods as a function of C_X for values of R_X and V_{DD} .

The output pulse width has variations of $\pm 2.5\%$ typically, over the temperature range of $-55^\circ C$ to $125^\circ C$ for $C_X = 1000$ pF and $R_X = 100$ k Ω .

For power supply variations of $\pm 5\%$, the output pulse width has variations of $\pm 0.5\%$ typically, for $V_{DD} = 10$ V and 15 V and $\pm 1\%$ typically, for $V_{DD} = 5$ V at $C_X = 1000$ pF and $R_X = 5$ k Ω .

These types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic package (E suffix), and in chip form (H suffix).

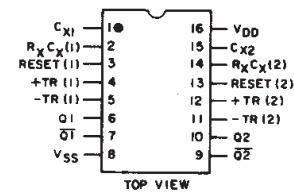
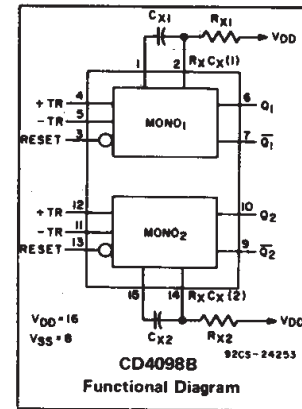
The CD4098B is similar to type MC14528.

Features:

- Retriggerable/resettable capability
- Trigger and reset propagation delays independent of R_X , C_X
- Triggering from leading or trailing edge
- Q and \bar{Q} buffered outputs available
- Separate resets
- Wide range of output-pulse widths
- 100% tested for maximum quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and $25^\circ C$
- Noise margin (full package-temperature range):
 - 1 V at $V_{DD} = 5$ V
 - 2 V at $V_{DD} = 10$ V
 - 2.5 V at $V_{DD} = 15$ V
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices."

Applications:

- Pulse delay and timing
- Pulse shaping
- Astable multivibrator



TERMINALS 1, 8, 15 ARE ELECTRICALLY CONNECTED INTERNALLY
92CS-24848RI
TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})	Voltages referenced to V_{SS} Terminal	-0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS		-0.5V to $V_{DD} + 0.5V$
DC INPUT CURRENT, ANY ONE INPUT		± 10 mA
POWER DISSIPATION PER PACKAGE (P_D):		
For $T_A = -55^\circ C$ to $+100^\circ C$		500mW
For $T_A = +100^\circ C$ to $+125^\circ C$		Derate Linearly at 12mW/ $^\circ C$ to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR		
For $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types)		100mW
OPERATING-TEMPERATURE RANGE (T_A)		$-55^\circ C$ to $+125^\circ C$
STORAGE TEMPERATURE RANGE (T_{stg})		$-85^\circ C$ to $+150^\circ C$
LEAD TEMPERATURE (DURING SOLDERING):		
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10s max		$+265^\circ C$

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V_{DD} V	LIMITS		UNITS
		MIN.	MAX.	
Supply-Voltage Range (For $T_A =$ Full Package-Temperature Range)	-	3	18	V
Trigger Pulse Width $t_W(TR)$	5 10 15	140 60 40	- - -	ns
Reset Pulse Width $t_W(R)$ (This is a function of C_X)	-	See Dynamic Char. Chart and Fig. 10		-
Trigger Rise or Fall Time $t_r(TR), t_f(TR)$	5 - 15	-	100	μs

CD4098B Types

TABLE I

CD4098B FUNCTIONAL TERMINAL CONNECTIONS

FUNCTION	V _{DD} TO TERM. NO.		V _{SS} TO TERM. NO.		INPUT PULSE TO TERM. NO.		OTHER CONNECTIONS	
	MONO ₁	MONO ₂	MONO ₁	MONO ₂	MONO ₁	MONO ₂	MONO ₁	MONO ₂
Leading-Edge Trigger/Retriggerable	3, 5	11, 13			4	12		
Leading-Edge Trigger/Non-retriggerable	3	13			4	12	5-7	11-9
Trailing-Edge Trigger/Retriggerable	3	13	4	12	5	11		
Trailing-Edge Trigger/Non-retriggerable	3	13			5	11	4-6	12-10
Unused Section	5	11	3, 4	12, 13				

NOTES:

1. A RETRIGGERABLE ONE-SHOT MULTIVIBRATOR HAS AN OUTPUT PULSE WIDTH WHICH IS EXTENDED ONE FULL TIME PERIOD (T_X) AFTER APPLICATION OF THE LAST TRIGGER PULSE. The minimum time between retriggering edges (or trigger and retrigger edges) is 40 per cent of (T_X).

2. A NON-RETRIGGERABLE ONE-SHOT MULTIVIBRATOR HAS A TIME PERIOD T_X REFERENCED FROM THE APPLICATION OF THE FIRST TRIGGER PULSE.

INPUT PULSE TRAIN



RETRIGGERABLE MODE PULSE WIDTH (+TR MODE)



NON-RETRIGGERABLE MODE PULSE WIDTH (+TR MODE)

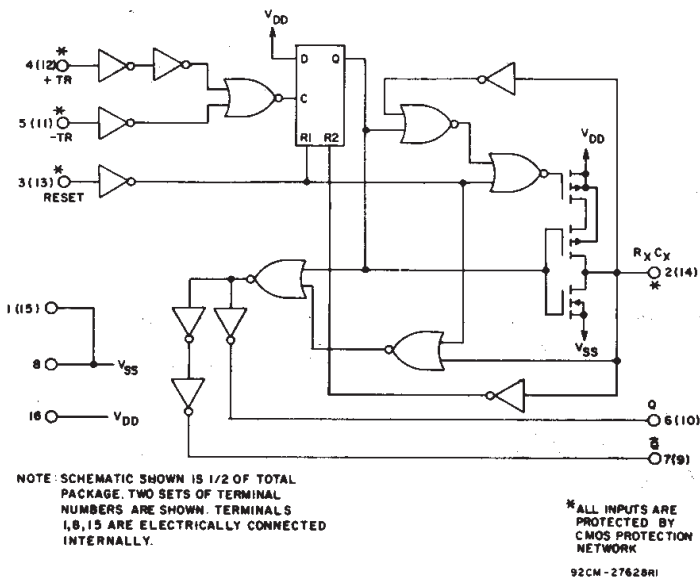
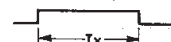


Fig. 4 - CD4098B logic diagram.

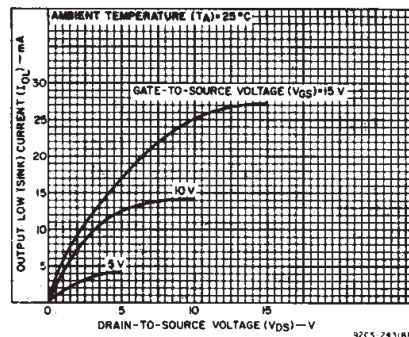


Fig. 1 - Typical output low (sink) current characteristics.

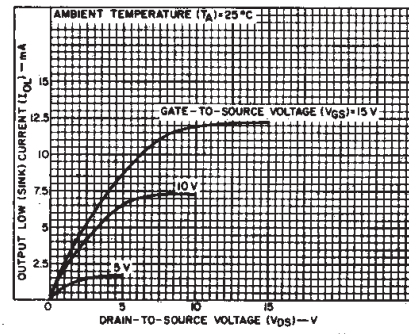


Fig. 2 - Minimum output low (sink) current characteristics.

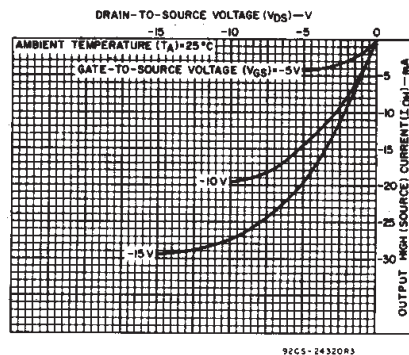


Fig. 3 - Typical output high (source) current characteristics.

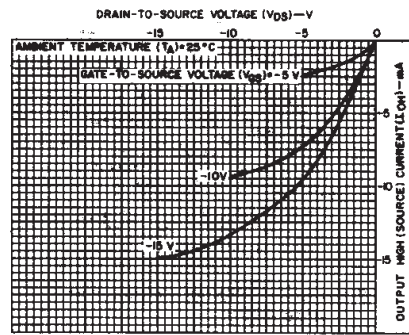


Fig. 5 - Minimum output high (source) current characteristics.

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4098B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current	—	0.5	5	1	1	30	30	—	0.02	1	μA
I _{DD} Max.	—	0.10	10	2	2	60	60	—	0.02	2	
	—	0.15	15	4	4	120	120	—	0.02	4	
Output Low (Sink) Current, I _{OL} Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
I _{OL} Max.	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I _{OH} Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA
I _{OH} Max.	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0.5	5	0.05			—	0	0.05	—	V
	—	0.10	10	0.05			—	0	0.05	—	
	—	0.15	15	0.05			—	0	0.05	—	
Output Voltage: High-Level, V _{OH} Min.	—	0.5	5	4.95			—	4.95	5	—	V
	—	0.10	10	9.95			—	9.95	10	—	
	—	0.15	15	14.95			—	14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	—	5	1.5			—	—	1.5	—	V
	1.9	—	10	3			—	—	3	—	
	1.5, 13.5	—	15	4			—	—	4	—	
Input High Voltage, V _{IH} Min.	0.5, 4.5	—	5	3.5			—	3.5	—	—	V
	1.9	—	10	7			—	7	—	—	
	1.5, 13.5	—	15	11			—	11	—	—	
Input Current, I _{IN} Max.	—	0.18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA
Output Leakage I _{OUT} Max.	0.18	0.18	18	±0.4	±0.4	±12	±12	—	±10 ⁻⁴	±0.4	μA

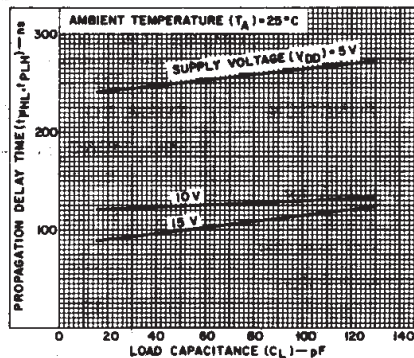


Fig. 6 - Typical propagation delay time vs. load capacitance, trigger into Q out. (All values of C_X and R_X)

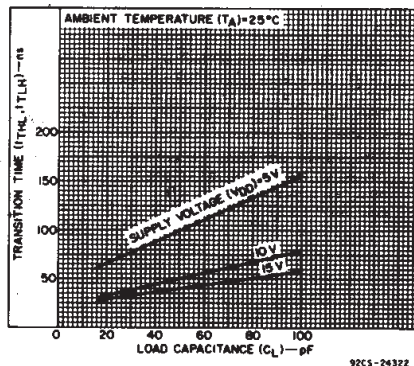


Fig. 7 - Transition time vs. load capacitance for R_X = 5 kΩ-10000 kΩ and C_X = 15 pF-10000 pF.

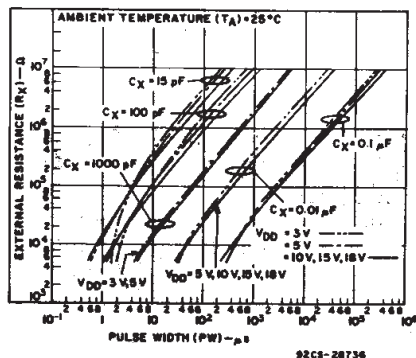


Fig. 8 - Typical external resistance vs. pulse width.

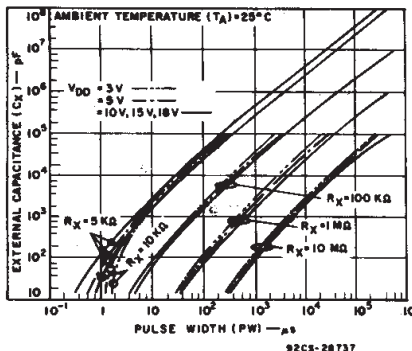


Fig. 9 - Typical external capacitance vs. pulse width.

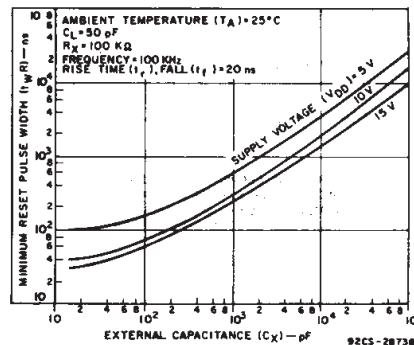


Fig. 10 - Typical minimum reset pulse width vs. external capacitance.

CD4098B Types

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^\circ\text{C}$; Input $t_r, t_f = 20\text{ ns}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTIC	TEST CONDITIONS			LIMITS		UNITS
	R_X (k Ω)	C_X (pF)	V_{DD} (V)	Typ.	Max.	
Trigger Propagation Delay Time +TR, -TR to Q, \bar{Q} t_{PHL} , t_{PLH}	5 to 10,000	≥ 15	5 10 15	250 125 100	500 250 200	ns
Minimum Trigger Pulse Width, t_{WH} , t_{WL}	5 to 10,000	≥ 15	5 10 15	70 30 20	140 60 40	ns
Transition Time, t_{TLH}	5 to 10,000	≥ 15	5 10 15	100 50 40	200 100 80	ns
t_{THL}	5 to 10,000	15 to 10,000	5 10 15	100 50 40	200 100 80	
	5 to 10,000	0.01 μF to 0.1 μF	5 10 15	150 75 65	300 150 130	
	5 to 10,000	0.1 μF to 1 μF	5 10 15	250 150 80	500 300 160	
Reset Propagation Delay Time, T_{PHL} , T_{PLH}	5 to 10,000	≥ 15	5 10 15	225 125 75	450 250 150	ns
Minimum Reset Pulse Width, t_{WR}	100	15	5 10 15	100 40 30	200 80 60	ns
		1000	5 10 15	600 300 250	1200 600 500	
		0.1 μF	5 10 15	25 15 10	50 30 20	μs
Trigger Rise or Fall Time t_r (TR), t_f (TR)	—	—	5 to 15	—	100	μs
Pulse Width Match Between Circuits in Same Package	10	10,000	5 10 15	5 7.5 7.5	10 15 15	%
Input Capacitance, C_{iN}	Any Input			5	7.5	pF

TEST CIRCUITS

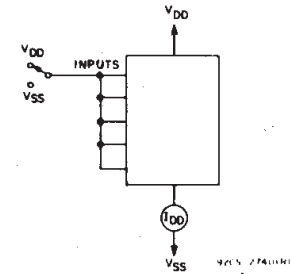


Fig. 12 - Quiescent-device-current test circuits.

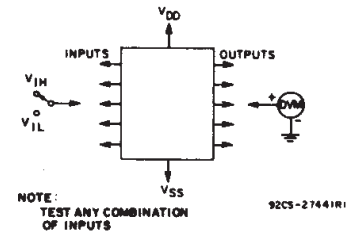


Fig. 13 - Input-voltage test circuit.

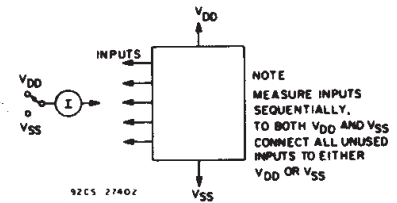
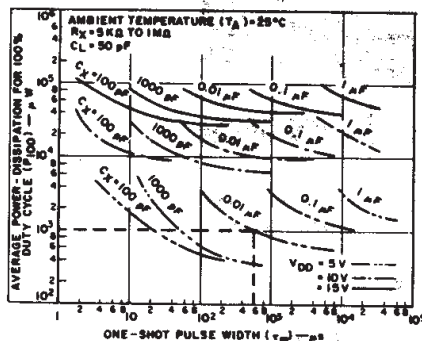
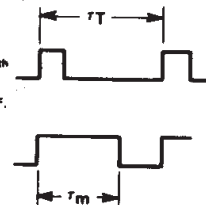


Fig. 14 - Input leakage current test circuit.



To calculate average power dissipation (P) for less than 100% duty cycle:
 P_{100} = average power for 100% duty cycle
 $P = \left(\frac{\tau_m}{T}\right) P_{100}$ where τ_m = one-shot pulse width
 T = trigger pulse period

e.g. For $\tau_m = 600\ \mu\text{s}$, $T = 1000\ \mu\text{s}$, $C_X = 0.01\ \mu\text{F}$,
 $V_{DD} = 5\text{ V}$
 $P = \left(\frac{600}{1000}\right) 10^{-3} = 600\ \mu\text{W}$ (see dotted line on graph)



92CN-20739

Fig. 11 - Average power dissipation vs. one-shot pulse width.

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4098B Types

APPLICATIONS

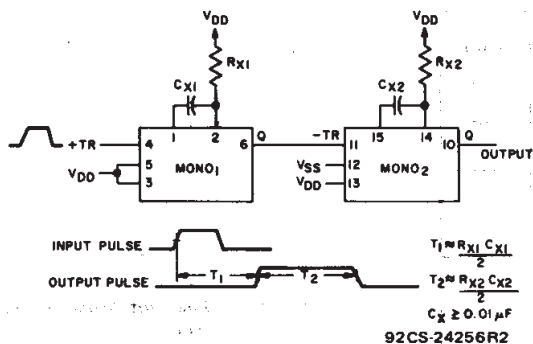


Fig. 15 - Pulse delay.

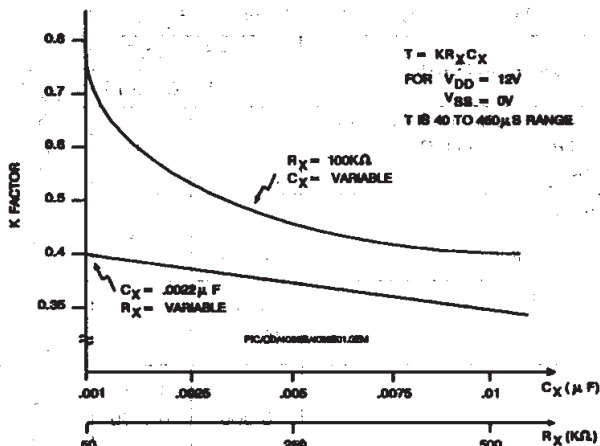


Fig. 17 - K-Factor for $V_{DD} = 12V$.

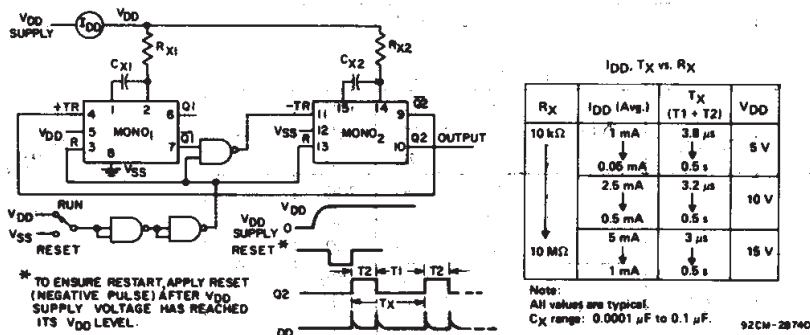
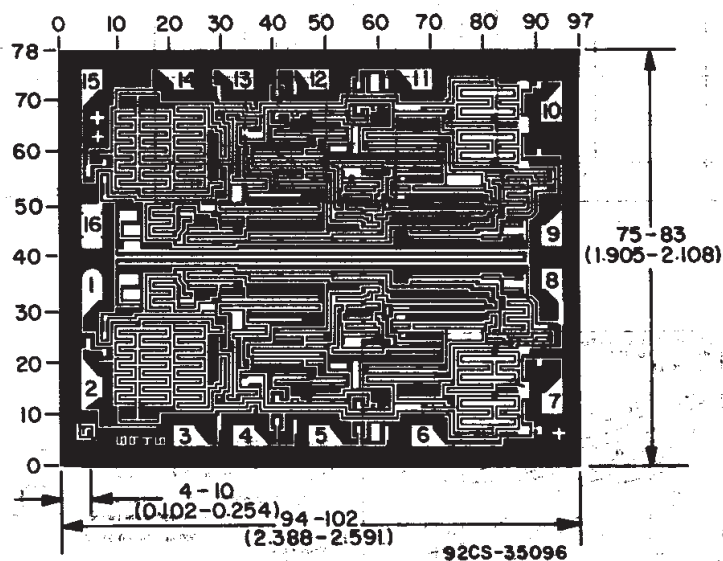


Fig. 16 - Astable multivibrator with restart after reset capability.



Dimensions and Pad Layout for CD4098BH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

This datasheet has been downloaded from:

www.DatasheetCatalog.com

Datasheets for electronic components.